Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	267	257/307.cds.	US-PGPUB; USPAT	OR	ON	2007/06/06 16:07
S2	28798	capacitor same electrode same dielectric and 257/307.ccls.	US-PGPUB; USPAT	OR	ON	2007/06/06 16:07
S3	163	capacitor same electrode same dielectric and 257/307.ccls.	US-PGPUB; USPAT	OR	ON	2007/06/06 16:08
S4	92	capacitor same electrode same dielectric and 257/307.ccls. and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 16:09
S5	14	capacitor same electrode same dielectric same conductor and 257/307.cds. and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 16:12
S6	0	capacitor same electrode same dielectric same conductor same semiconductor layer and 257/307.ccls. and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/06 16:11
S7	0	capacitor same electrode same dielectric same conductor same energization and 257/307.cds. and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 16:12
S8	2	capacitor same electrode same dielectric same conductor same energization and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 16:12
S9	0	capacitor same electrode same dielectric same conductor same semiconductor same energization and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 16:13
S10	2	capacitor same electrode same dielectric same conductor same semiconductor same energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:34
S11	106	naito-kazumi.in.	US-PGPUB; USPAT	OR	ON	2007/06/06 18:02
S12	373437	capacitor conductor same semiconductor same energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:23
S13	19	capacitor same conductor same semiconductor same energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:24
S14	6	capacitor same conductor same semiconductor with energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:25
S15	54	capacitor same semiconductor with energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:27
S16	29	semiconductor with conductor with energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:28
S17	0	semiconductor near conductor near energization	US-PGPUB; USPAT	OR	ON	2007/06/06 16:28
S18	15	capacitor same electrode same dielectric same conductor same semiconductor same energization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 16:49
S19	2468	capacitor same electrode with dielectric with conductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 16:39
S20	7	capacitor same electrode near dielectric near conductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 16:39

S21	0	method of manufacturing a capacitor	US-PGPUB;	ADJ	ON	2007/06/06 16:50
			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S22	0	method of manufacturing a capacitor.ti.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2007/06/06 16:51
			IBM_TDB			
S23	1185	method manufacturing capacitor.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2007/06/06 16:52
S24	849	method manufacturing capacitor.ti. and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2007/06/06 16:59
S25	0	S24 and energization	US-PGPUB; USPAT	OR	ON	2007/06/06 17:01
S26	5	S24 and protrusion	US-PGPUB; USPAT	OR	ON	2007/06/06 17:31
S27	1613313	S24 and protrusion with dielectric layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:31
S28	0	S24 and protrusion with dielectric layer	US-PGPUB; USPAT	ADJ	ON	2007/06/06 17:31
S29	. 1	S24 and protrusion same dielectric layer	US-PGPUB; USPAT	ADJ	ON	2007/06/06 17:31
S30	5	("4977098" "5037773" "5043780" "5135886" "5208479").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/06 17:34
S31	. 0	capacitor with dielectric adj layer with portrusions	US-PGPUB; USPAT	OR	ON	2007/06/06 17:35
532	33	capacitor with dielectric adj layer with protrusions	US-PGPUB; USPAT	OR	ON	2007/06/07 08:01
S33	177	capacitor with dielectric with metal with (silicon or semiconductor) adj layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:41
S34	0	capacitor with fine adj protrusions with dielectric with metal with (silicon or semiconductor) adj layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:41
S35	0	capacitor with protrusions with dielectric with metal with (silicon or semiconductor) adj layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:41
S36	0	capacitor same protrusions with dielectric with metal with (silicon or semiconductor) adj layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:42
S37	177	capacitor with dielectric with metal with (silicon or semiconductor) adj layer	US-PGPUB; USPAT	OR	ON	2007/06/06 17:42
S38	100	capacitor with dielectric with metal with (silicon or semiconductor) adj layer and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/06 17:43
S39	52	361/122.cds.	US-PGPUB; USPAT	OR	ON	2007/06/06 18:03
S40	0	S39 and capacitor	US-PGPUB; USPAT	OR	ON	2007/06/06 18:03
S41	431674	electrolytic capacitor	US-PGPUB; USPAT	OR	ON	2007/06/07 07:32

			-			
S42	7541	electrolytic capacitor	US-PGPUB; USPAT	ADJ	ON	2007/06/07 07:32
S43	83	electrolytic capacitor same semiconductor layer	US-PGPUB; USPAT	AD3	ON	2007/06/07 07:41
544	2	electrolytic capacitor same dielectric layer with protrusions	US-PGPUB; USPAT	ADJ	ON	2007/06/07 07:42
S45	. 0	electrolytic capacitor same oxide layer with protrusions	US-PGPUB; USPAT	ADJ .	ON	2007/06/07 07:42
S46	1	electrolytic capacitor same oxide with protrusions	US-PGPUB; USPAT	ADJ	ON	2007/06/07 07:43
S47	44	capacitor with dielectric adj layer with protrusions	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/07 08:16
S48	62	electrolytic capacitor same form same semiconductor same volt\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:22
S49	0	electrolytic capacitor same form same semiconductor same electolytic polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:23
S50	0	electrolytic capacitor same form same organic same electolytic polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:24
S51		electrolytic capacitor same electolytic polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:24
S52	13	electrolytic capacitor same semiconductor same electrolytic polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:55
S53	6	("4724053" "4943892" "4959753" "5140502" "5174867" "5187650").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/07 08:26
S54	0	electrolytic capacitor same protrusions same before same semiconductor same electrolytic polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/07 08:56

Same electrolytic polymerization	06/07 08:56 06/07 08:56 06/07 09:32 06/07 14:24 06/07 14:28 06/07 14:42
Dolymerization USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB USPAT; USOCR "5473503").PN.	06/07 09:32 06/07 14:24 06/07 14:28 06/07 14:42
S57 10 ("4085435" "4110815" "4785380" "4805074" "4934033" US-PGPUB; USPAT; USOCR USPAT; USOCR USPAT	06/07 14:24 06/07 14:28 06/07 14:42
S59 S52 electrolytic capacitor and "29".clas. and @py<"2004" US-PGPUB; US-PGPU	06/07 14:28 06/07 14:42
S60 6 electrolytic capacitor same dielectric same protruding and "29". US-PGPUB; ADJ US-PGPUB; US-PG	06/07 14:42
Clas. and @py<"2004" USPAT USPAT OR ON 2007/6	·
S62 10 electrolytic capacitor same dielectric same protru\$4 and "29". US-PGPUB; ADJ USPAT USPAT USPAT USPAT USPAT OR USPAT USPAT OR USPAT USPA	06/07 14:41
Clas. and @py<"2004" USPAT USPAT US-PGPUB; OR USPAT;	
S64 16 ("2753331" "3634110" "4219382" "4468291" "4487667" US-PGPUB; OR ON 2007/\(\begin{array}{cccccccccccccccccccccccccccccccccccc	06/07 14:42
"4547270" "4566955" "4582575" "4582587").PN. OR	06/07 16:57
"4785380" "4803596").PN. USPAT;	06/08 10:01
South	06/08 10:09
S66 26 ("3454473" "3621342" "4009424" "4105513" "4580855" US-PGPUB; OR USPAT; USOCR ON 2007/0	06/08 10:26
95 electrolytic capacitor with inorganic semiconductor US-PGPUB; WITH ON 2007/9	06/08 10:27
S68 95 electrolytic capacitor with inorganic semiconductor US-PGPUB; USPAT ON 2007/9	06/08 10:39
S69 206 capacitor with inorganic semiconductor US-PGPUB; USPAT ON 2007/0	06/08 10:40
S70 216 electrolytic capacitor with inorganic US-PGPUB; USPAT ON 2007/0	06/08 10:59
S71 0 py<"2004" US-PGPUB; WITH ON 2007/9	06/08 10:40
S72 106 electrolytic capacitor with inorganic and @py<"2004" US-PGPUB; USPAT ON 2007/0	06/08 10:41
S73 16 electrolytic capacitor with inorganic same (molybdenum dioxide or tungsten dioxide or lead dioxide or manganese dioxide) and @py<"2004" USPAT USPAT USPAT	06/08 10:59
S74 352 electrolytic capacitor with conductivity US-PGPUB; ADJ ON 2007/0	06/08 12:58
S75 11 electrolytic capacitor near conductivity and @py<"2004" US-PGPUB; ADJ ON 2007/0	06/08 12:59
S76 2686 (semiconductor or solid electrolyte) near conductivity and US-PGPUB; ADJ ON 2007/0 USPAT	JU/ UU 12:33

		ZAST Scaren misc				
S77	282	(solid electrolyte) near conductivity and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 13:05
S78	3	electrolytic capacitor same (semiconductor or solid electrolyte)layer near conductivity and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 13:06
S79	1	("4959753").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 13:06
S80	. 24	("4780796" "4785380" "4803596").PN. OR ("4959753"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 13:07
S81	9	("4780796" "4803596" "4910645" "4959753" "5223120" "5225495" "5436796" "5455736" "5473503").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 13:17
S82	1	capacitor same impregnat\$3 with semiconductor with 85%	US-PGPUB; USPAT	OR	ON	2007/06/08 13:18
S83	. 42	capacitor same impregnat\$3 with semiconductor	US-PGPUB; USPAT	OR	ON	2007/06/08 13:18
S84	24	capacitor same impregnat\$3 with semiconductor and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/08 13:19
S85	2088	capacitor same (impregnat\$3 or doped) with semiconductor and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/08 13:20
S86	15	electrolytic capacitor same (impregnat\$3 or doped) with semiconductor and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 15:07
S87	322	electrolytic capacitor same semiconductor and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 15:07
S88	4	electrolytic capacitor same laminated near conductor and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 15:19
S89	0	protrusions same ".1" near "60" near nm	US-PGPUB; USPAT	ADJ	ON	2007/06/08 15:20
S90	38	protrusions same electrolytic capacitor	US-PGPUB; USPAT	ADJ	ON	2007/06/08 15:20
S91	10	("4085435" "4110815" "4785380" "4805074" "4934033" "5198967" "5428500" "5432029" "5443602" "5473503").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 15:24
S92	125315	manganese dioxide near (spot or island)	US-PGPUB; USPAT	OR	ON	2007/06/08 15:32
S93	1	manganese dioxide near (spot or island)	US-PGPUB; USPAT	SAME	ON	2007/06/08 15:48
S94	26	("3454473" "3621342" "4009424" "4105513" "4580855" "4785380" "4803596").PN. OR ("4943892").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 15:32
S95	0	dielectric same manganese dioxide near (spot or island)	US-PGPUB; USPAT	SAME	ON.	2007/06/08 15:49
S96	10	dielectric same dioxide near (spot or island)	US-PGPUB; USPAT	SAME	ON	2007/06/08 15:49
S97	15	("4697000" "4803596" "4910645" "4943892" "5236627" "5482655" "5766515" "5792558" "6001281" "6128180" "6151205" "6219223" "6229689" "6344966" "6381121").PN.	US-PGPUB; USPAT; USOCR	OR .	ON	2007/06/08 17:22
S98	8	("3454473" "3621342" "4009424" "4105513" "4580855" "4785380" "4803596").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 16:05
\$99	7	fine adj (protrusions or islands or feather-like or spots) same capacitor	US-PGPUB; USPAT	OR	ON	2007/06/08 16:08
S10 0	5039	(protrusions or islands or feather-like or spots) same capacitor	US-PGPUB; USPAT	OR	ON	2007/06/08 16:08

S10 1	5044	(protrusions or islands or feather or spots) same capacitor	US-PGPUB; USPAT	OR	ON	2007/06/08 16:08
S10 2	12.	fine adj (protrusions or islands or feather-like or spots) same capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/08 16:50
S10 3	Ö	fine manganese oxide particles same capacitors	US-PGPUB; USPAT;	ADJ	ON	2007/06/08 16:24
			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S10 4	4	fine manganese oxide particles	US-PGPUB; USPAT; USOCR;	ADJ	ON	2007/06/08 16:24
			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S10 5	195	fine adj (protrusions or islands or feather-like or spots or grain) same capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	OR	ON	2007/06/08 16:51
			DERWENT; IBM_TDB			
S10 6	0	py<"2004"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/08 16:51
S10 7	162	fine adj (protrusions or islands or feather-like or spots or grain) same capacitor and @py<"2004"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/08 16:52
S10 8	0	manganese dioxide near conductive polymer film	US-PGPUB; USPAT	ADJ	ON	2007/06/08 17:23
S10 9	. 45	manganese dioxide near conductive polymer	US-PGPUB; USPAT	ADJ	ON	2007/06/08 18:01
S11 0	.i 15	manganese dioxide near conductive polymer and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 17:26
S11 1	2	manganese dioxide near protrusions and @py<"2004"	US-PGPUB; USPAT	ADJ	ON	2007/06/08 17:27
S11 2	. 5	("5621608" "6110234" "6185091" "6224639" "6262878").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 17:28
S11 3	26	("3454473" "3621342" "4009424" "4105513" "4580855" "4785380" "4803596").PN. OR ("4943892").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 18:09
S11 4	15	("4697000" "4803596" "4910645" "4943892" "5236627" "5482655" "5766515" "5792558" "6001281" "6128180" "6151205" "6219223" "6229689" "6344966" "6381121").PN. OR ("7221554").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 18:22

S11 5	15	("3345545" "4090231" "4943892" "5075940" "5586001" "5949639" "5951840" "5959831" "5965062" "6042740").PN. OR ("6191936").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/08 18:23
S11 6	3	"3454473"	US-PGPUB; USPAT	OR	ON	2007/06/11 11:45
S11 7	8	"3621342"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:17
S11 8	17	"4580855"	US-PGPUB; USPAT	OR .	ON	2007/06/11 12:22
S11 9	682	capacitor same dielectric same (protrusions island feather)	US-PGPUB; USPAT	OR	ON	2007/06/11 12:23
S12 0	390	capacitor same dielectric same (protrusions island feather)and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:39
S12	4	electrolytic adj capacitor same dielectric same (protrusions island feather)and @py<"2004"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:23
S12 2	2	"3174209"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:39
S12 3	6	"3241008"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:42
S12 4	5	"3481029"	US-PGPUB; USPAT	OR	ON	2007/06/11 12:46
S12 5	0	fine adj protrusion with dielectric with (nano\$met\$3 or nanometer)	US-PGPUB; USPAT	OR	ON	2007/06/12 07:58
S12 6	3	protrusion with dielectric with (nano\$met\$3 or nanometer)	US-PGPUB; USPAT	OR	ON	2007/06/12 07:59
S12 7	10	islands with dielectric with (nano\$met\$3 or nanometer)	US-PGPUB; USPAT	OR	ON	2007/06/12 08:01
S12 8	46	islands with insulat\$4 with (nano\$met\$3 or nanometer)	US-PGPUB; USPAT	OR	ON	2007/06/12 08:09
S12	18	islands with oxide with (nano\$met\$3 or nanometer)	US-PGPUB; USPAT	OR	ON	2007/06/12 08:09
S13 0	3	("4980341" "5053383" "5157466").PN.	US-PGPUB; USPAT;	OR ·	ON	2007/06/12 08:16
S13	229	forming with oxide with protrusions	USOCR US-PGPUB; USPAT	OR	ON	2007/06/12 08:18
S13 2	229	forming with oxide with protrusions and ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 08:18
S13	177	forming with oxide with protrusions and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 08:19
S13	3	forming with oxide with (protrusions or islands)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 08:21
S13 5	10	forming with (oxide or insula\$4 or dielectric) with (protrusions or islands)with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 10:16
S13	10	forming with (oxide or insula\$4 or dielectric) with (protrusions or islands or feather-like)with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 10:17
S13 7	17	forming with (oxide or insula\$4 or dielectric) with (protrusions or islands or feather-like)with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:24

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S13 8	922	(protrusions or islands or feather-like)with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:25
S13 9	163	(protrusions or islands or feather-like)with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926" and "438". clas.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:29
S14 0	2	forming same (protrusions or islands or feather-like)with oxidation with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926" and "438".clas.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:29
S14 1	4	forming same (protrusions or islands or feather-like)with oxid\$6 with (nanometer or nano\$met\$3 or micrometer) and @ad<"20030926" and "438".clas.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:30
S14 2	4716944	metal oxide with form with (protrusions or island or grains) with (dielectric or insulator or oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:32
S14 4	571	metal oxide with form with (protrusions or island or grains) with (dielectric or insulator or oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 10:32
S14 5	439	metal oxide with form with (protrusions or island or grains) with (dielectric or insulator or oxide)and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 10:36
S14 6	2	metal oxide with form with (protrusions or island or grains) with (dielectric or insulator or oxide)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 10:39
S14 7	2	roughe\$4 near (dielectric or insulator or oxide)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 10:47

S14 8	258	roughe\$4 near (dielectric or insulator or oxide) and @ad<"20030926"	US-PGPUB; USPAT; USOCR;	ADJ	ON	2007/06/12 10:40
			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S14 9	0	fine protrusions near(dielectric or insulator or oxide)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ОЙ	2007/06/12 10:48
S15 0	0	fine protrusions with(dielectric or insulator or oxide)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 10:48
S15 1	· · · · 4	protrusions with(dielectric or insulator or oxide)with (nanometer or nano\$met\$3) and @ad<"20030926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/06/12 12:27
S15 2	0	thermal decpomposition with manganese oxide with (dielectric or insulator or oxide)with (island or protrusion or grain) with (nano\$mete\$\$ or nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:29
S15 3	0	thermal decomposition with manganese oxide with (dielectric or insulator or oxide) with (island or protrusion or grain) with (nano\$mete\$\$ or nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:29
S15 4	., 0	thermal with manganese oxide with (dielectric or insulator or oxide)with (island or protrusion or grain) with (nano\$mete\$3 or nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:29
S15 5	0	manganese oxide with (dielectric or insulator or oxide)with (island or protrusion or grain) with (nano\$mete\$\$ or nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:29
S15 6	0	manganese oxide with (dielectric or insulator or oxide)with (island or protrusion or grain) with (nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:30
S15 7	1	manganese dioxide with (dielectric or insulator or oxide)with (island or protrusion or grain) with (nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:31
S15 8	6	manganese dioxide with (island or protrusion or grain) with (nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:31
S15 9	0	manganese dioxide with (island or protrusion) with (nanometer or micrometer or micron or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:31
S16 0	56	dioxide with (island or protrusion) with (nanometer or micrometer or microm or "MU")	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:32
S16 1	29	dioxide with (island or protrusion) with (nanometer or micrometer)	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:36
S16 2	0	dioxide with nano near (island or protrusion) with (nanometer or micrometer)	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:34
S16 3	6	dioxide with nano with(island or protrusion) with (nanometer or micrometer)	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:34

S16 4	2	("4551192" "5463526").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/12 12:34
S16 5	20	dioxide with (island or protrusion) with (nanometer)	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:36
S16 6	0	thermal decomposi\$4 same capactor	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:37
S16 7	261	thermal decomposi\$4 same capacitor	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:37
S16 8	220	thermal decomposi\$4 same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:38
S16 9	0	thermal decomposi\$4 with (islands or protrusions or spots or fingers or bumps)with nanometer same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:38
S17 0	0	thermal decomposi\$4 with (islands or protrusions or spots or fingers or bumps) same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:38
S17 1	220	thermal decomposi\$4 same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:50
S17 2	, · O	thermal decomposi\$4 same protrusions same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:50
S17 3	1	thermal decomposi\$4 same islands same capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 12:50
S17 4	8	("3454473" "3621342" "4009424" "4105513" "4580855" "4785380" "4803596").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/12 13:06
S17 5	0	pyrolisis with protrusions	US-PGPUB; USPAT	OR	ON	2007/06/12 13:08
S17 6	463	protrusions with islands	US-PĢPUB; USPAT	OR	ON	2007/06/12 13:08
S17 7	273	protrusions with islands and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:49
S17 8	14	protrusions with islands with (dielectric or oxide or insulator) and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:11
S17 9	144527	protrusion and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:12
S18 0	32	nano near capacitor	US-PGPUB; USPAT	OR	ON	2007/06/12 13:32
S18 1	0	nano near size near capacitor	US-PGPUB; USPAT	OR	ON	2007/06/12 13:32
S18 2	12	nano near capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:33
\$18 3	0	nanoscale near capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:33
S18 4	85	nanoscale same capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:36
S18 5	33631	size same capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:37
S18 6	562	nano same capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:37
S18 7	3	nano adj capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:37
S18 8	0	protrusions with islands with angstroms and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 13:49
S18 9	2	protrusions with islands with nm and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 14:47

S19 0	ì	2	"20050247928" .	US-PGPUB; USPAT	OR	ON	2007/06/12 13:53
S19 1	···	729	conductor with anode with capacitor	US-PGPUB; USPAT	OR	ON	2007/06/12 14:47
S19 2		650	conductor with anode with capacitor and @ad<"20030926"	US-PGPUB; USPAT	OR	ON	2007/06/12 14:48
S19 3		509	metal with anode with electrolytic capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 14:48
S19 4	÷	132	metal near anode with electrolytic capacitor and @ad<"20030926"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 15:04
S19 5		1	"60507942"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 15:08
S19 6		47	"5473503"	US-PGPUB; USPAT	ADJ	ON	2007/06/12 15:08
S19 7		9	"4724053"	US-PGPUB; USPAT	OR	ON	2007/06/13 10:25